

11th Joint MMM-Intermag Conference

17-21 January 2010, Washington, DC

BKQ

The Physics Based Human Resources Development Program for the Next Generation Devices

Structural and Magnetic Properties of FesoMnso Nanocrystalline Alloys

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Introduction

Mechanical Alloying (MA) process is an effective way to fabricate nanocrystalline alloys and their physical properties are related to structural variations.

Some regularity in atomic arrangement in solids can be classified by the short-range order (SRO) and long-range order (LRO). Among these, LRO is frequently examined by X-ray diffraction studies while SRO could be examined by extended X ray absorption fine structure (EXAFS).

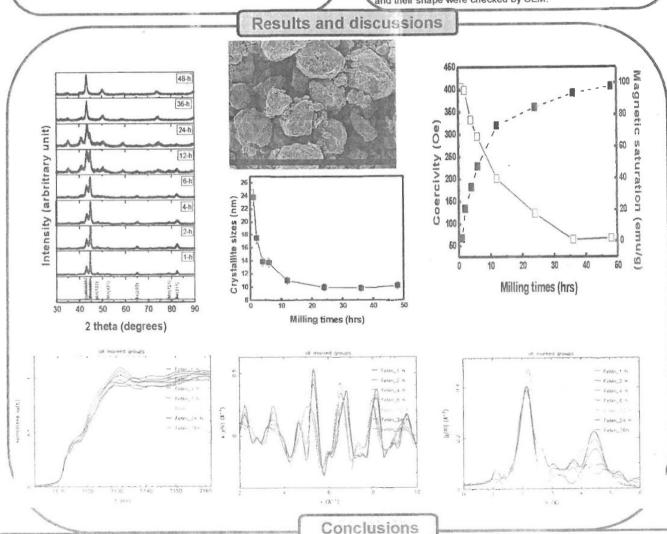
Fe-Mn alloys have been studied extensively for many applications in electromagnetic devices, such as magnetic sensors and spin-valve reading/recording heads

In this work, we present preparation and characterization of the structure and magnetic behavior of FessMnso alloys as changing the milling time.

Experiment

Fe₅₀Mn₅₀metastable alloys were prepared by MA. The starting material was a mixture of pure Fe and Mn powders (used commercial Fe and Mn powders as the precursors). The weight ratio of balls-to-powder mixture was 5:1. Fe₅₀Mn₅₀ alloys were mixed and ground for different times of 1, 2, 4, 6, 12, and 24 hrs in Ar ambient to prevent oxidation during the alloying process.

Magnetic measurements were carried out on SQUID. XRD using the Cu-K_o radiation. Based on these data, crystallite size estimated with Scherrer formula. EXAFS data were operated with an energy of 2.5 GeV, and a maximum current of 200 mA. EXAFS spectra were obtained at Fe K-edge (7112 eV) in the transmission mode at room temperature. The sample chamber was filled with pure nitrogen gas. The EXAFS data were analyzed by FEFF software. Finally, the nanoparticle size and their shape were checked by SEM.



The formation of Fe₅₀Mn₅₀ metastable alloys is explicitly shown in the EXAFS spectra by the variation of amplitude and phase between 12 hrs and 24 hrs milling times. The significant change of the structural phase revealed that new atom neighbors between the central Fe and Mn atoms increased during the MA process. The Fe and Mn atoms are diffused each other to form the FeMn alloy phase.

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General Information

SCOPE OF THE CONFERENCE

The 11th Joint MMM/Intermag Conference is sponsored jointly by the American Institute of Physics (PCI) and the Magnetics Society of the IEEE, in cooperation with The American Physical Society. Members of the international scientific and engineering communities interested in recent developments in fundamental and applied magnetism are invited to attend the Conference and contribute to its technical sessions. Sessions will include invited and contributed papers, oral and poster presentations and invited symposia. This Conference provides an outstanding opportunity for participants to meet their colleagues and discuss new, advanced and controversial developments.

WASHINGTON, DC

The 2010 Joint Conference will be held in the nation's capital. The city welcomes 15 million visitors each year of which 1.2 million are international. There are more than 100 restaurants located in the downtown area alone, and the city has been called "one of the most exciting restaurant cities on the East Coast" by Travel & Leisure. To obtain an in-depth and current view of what to see and do while you are here, visit the official website at: http://www.washington.org. Here you will find information on how to travel to the Marriott Washington Wardman Park from any of the three local airports; you can check on the weather in mid-January, and can request a free Visitors Guide prior to making your trip.

VISA REQUIREMENTS

The US has updated its visa policies to increase security, so it may take you 3-6 months to apply for and receive your visa. For details that apply specifically to your country please go immediately to your nearest US Consulate or Embassy. Review your visa status now to determine if you need a US visa or visa renewal and to find out how to schedule an interview appointment, pay fees, and receive other vital instructions. If you need a personal letter of invitation to attend the Conference, contact the Conference Coordinators by Email at: 2010JointConf@widerkehr.com. Please provide the following information: Complete name, mailing address, and any other details that your country of residence requires for your visa application. If you need a hard copy of the invitation to be mailed to you, please indicate this in your request. Otherwise the invitation will be sent to you by reply email. The Joint Conference cannot contact or intervene with any U.S. Embassy or Consulate office abroad on your behalf, so please begin your visa application process as soon as you determine that you want to attend the 2010 Joint Conference.

NEW VISA WAIVER PROGRAM TRAVEL: Beginning 12 January 2009, all nationals and citizens of Visa Waiver Program (VWP) countries (http://www.travel.state.gov/visa/temp/without/without_1990.html#countries) who plan to travel to the U.S. for temporary business or pleasure for 90 days or less will be required by law to obtain travel authorization prior to initiating travel to the United States. This authorization can be obtained online through the Electronic System for Travel Authorization (http://www.cbp.gov/xp/cgov/travel/id_visa/esta/) (ESTA), a free Internet application administered by the U.S. Department of Homeland security (http://www.dbs.gov/index.shtm). For additional information about the ESTA please visit http://www.cbp.gov/esta.Travelers from countries not

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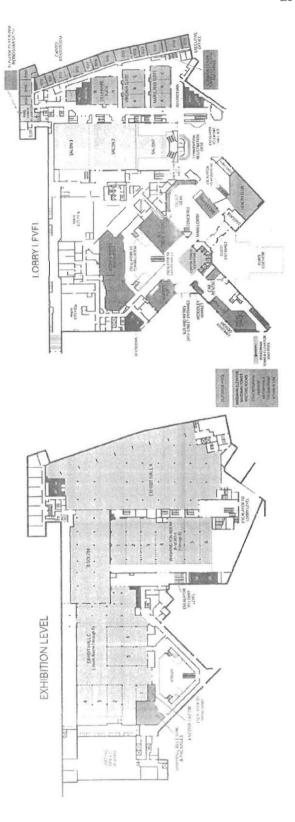
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CONFERENCE PROGRAM

Mon eve 7:00 p.m.	XA	Magnetization switching below the Stoner-Wohlfarth limit	Salon 2
7.00 p.m.		Storet-wantath him	Descore in
Tuesday	ΔΔ	Symposium: Spin torque devices for	
9:00 a.m.	nn;	CMOS-integrated applications	Salon 2
	AB	Magnetization dynamics and damping I	Salon 3
	AC	Giant magnetoresistance I	Delaware
	AD	Recording physics and measurements	Virginia
	ΑĒ	Superconductivity I	Washington 1
	AF	Magnetoresistive oxides: Phase behavior and ordering	Washington 2
	AG	Magnetic sensors I (Not magnetic recording)	Washington 3
	ΑĦ	Biosensing and MRI	Washington 5
8:00 a.m.	ΑP	Bulk magnetoresistive oxides	Exhibit Hall C
	AQ	Magnetoresistive oxide thin films	Exhibit Hall C
	AR	Spm current and spin Hall effect	Exhibit Hall C
	AS	Amorphous and nanocrystalline soft magnets I	Exhibit Hall C
	АΥ	Magnetocaloric materials I	Exhibit Hall C
	ΑU	Magnetocaloric materials II	Exhibit Hall C
	ΑV	Hard magnets: RTM5 and Co-based magnets	Exhibit Hall C
	AW	Hard magnets: FePt	Exhibit Hall C
	ΑX	Nanoparticles and nanowires	Exhibit Hall C
	ΑY	Nanoparticles I	Exhibit Hall C
2:00 p.m.	ВА	Spin-torque devices: Dynamics and advanced materials	Salon 2
	ВВ	Energy assisted magnetic recording	Salon 3
	BC	Magnetic microscopy I	Delaware
	BD	Exchange bias I	Virginia
	BE	Spin injection in semiconductors	Washington 1
	BF	Multiferroics: Novel materials	Washington 2
	BG	Magnetoelastic materials I	Washington 3
	ВН	Hard magnets: R1TMS and FePt	Washington 5
1:00 p.m.	BP	Multiferroics: Thin films and composites	Exhibit Hall C
	BQ	Multiferroics: Bulk and nanomaterials	Exhibit Hall C
	BR	Ultrathin films and surface effects I	Exhibit Hall C
	BS	New magnetic materials I	Exhibit Hall C
	вт	Magnetoelastic materials II	Exhibit Hall C
	вυ	Magnneto-optic microwave	Exhibit Hall C
		and molecular magnet materials	
	ΒV	ferrite magnets I	Exhibit Hall C
	BW	Ferrite magnets II	Exhibit Hall C
-	▶BX	Crystalline soft magnets and domains l	Exhibit Hall C
	BY	New applications	Exhibit Hall C
7:00 p.m.	BZ	Symposium: Large scale facilities for magnetism research	Salon 2

Wednesday 9:00 a.m.	CB	Multiferroics: Thin films and tunnel junctions	Salon 2 Salon 3	Thur 'ay 9:00 a.m	EA EB	Spin-torque Devices: Oscillators Dynamics Symposium: Recent Advances in Microscopy of Magnetyic Materials	Salon 2 Salon 3
	CC	CPP-GMR reader technology	Delaware		EC	Magnetization Dynamics & Damping II	Delaware
	CD	Symposium: Spin injection into nonmagnetic media	Virginia		ED	Magnetic Recording: Continuous Granular Media	Virginia
	CE	Ferrite magnets III	Washington 1		EE	Electronic Structure and Low Dimensionality	Washington 1
	CF	Micromagnetics and hysteresis modeling I	Washington 2		CL	Systems I	-
	CG	Patterned films l	Washington 3		EF	Spin Currents, Spin Hall Effects	Washington 2
	CH	Hyperthermia and other applications	Washington 5			and Tunnel Magnetoresistance	
		of nanoparticles			EG	MEMS, High Frequency Devices and Shielding	Washington 3
8:00 a.m.	CP	Electrical machines and levitation	Exhibit Hall C		EH	Nanoparticle Composites	Washington 5
	CQ	Special machines and actuators	Exhibit Hall C				
	CR	Linear machines and actuators	Exhibit Hall C	8:00 a.m	EP	Other Half Metals I	Exhibit Hall C
	CS	PM machines I	Exhibit Hall C		EQ	Magnetoelectronic Materials and Effects	Exhibit Hall C
	CT	PM machines II	Exhibit Hall C		ER	Magnetic Semiconductors: Oxides	Exhibit Hall C
	CU	Reluctance machines	Exhibit Hall C			and Other Materials	
	CV	Head-disk interface and integration	Exhibit Hall C		ES	Magnetic Semiconductors: ZnO	Exhibit Hall C
	CW	Magnetic recording - FePt media	Exhibit Hall C		ET	Tunnel Magnetoresistance I	Exhibit Hall C
	CX	Magnetic recording: Continuous granular media	Exhibit Hall C		EU	Tunnel Magnetoresistance II	Exhibit Hall C
	CY	Bit patterned media I	Exhibit Hall C		EV	Tunnel Magnetoresistance III	Exhibit Hall C
					EW	Domain Wall Devices and Spin Transfer Torque	Exhibit Hall C
1:30 p.m.	DA	MRAM and Spin-Torque Switches	Salon 2		EX	Domain Wall Devices I	Exhibit Hall C
	DB	Ultrafast Dynamics	Salon 3		ΕY	Spin-torque Devices: Oscillators and Dynamics	Exhibit Hall C
	DÇ	Symposium: Advanced motor and actuator technologies	Delaware	2.00 n m	FA	Domain Wall Dynamics	Salon 2
	DD	Symposium: Spin-Calorics	Virginia	2:00 p.m.	FB	Timnel Magnetoresistance IV	Salon 3
	DE	Correlated Electron Materials I	Washington 1			Symposium: Magnetic Medical	Delaware
	DF	Magneto-Optic and Microwave Materials	Washington 2		FC	Imaging Technology	
	DG	Inductive Write Heads	Washington 3		FD	Bit-Patterned Media II	Virginia
	DH	Nanoparticles II	Washington 5		FE	Amorphous and Nanocrystalline Soft Magnets II	Washington 1
	Dil	танорагиенез п			FF	Magnetic Semiconductors: III-V	Washington 2
1:00 p.m.	DP	Micromagnetics and Hysteresis Modeling II	Exhibit Hall C		FG	New Magnetic Materials II	Washington 3
1.00 p.m.		Hard Magnets: Theory and Oxides	Exhibit Hall C		FH		Washington 5
	DQ	Giant Magnetoresistance II	Exhibit Hall C		* * * *	and Frustration 1	
	DR	Spin Injection in Semiconductors: Organic	Exhibit Hall C				
1	DS	and Granular Spin-Valves	Editor Hall C	1:00 p.m.	FP	Superconductivity II	Exhibit Hall C
	DT	MRAM and Giant Magnetoresistance	Exhibit Hall C		FQ	Correlated Electron Materials II	Exhibit Hall C
	DU	The second secon	Exhibit Hall C		FR	Electronic Structure and Low Dimensionality	Exhibit Hall C
	DV	Patterned Films II	Exhibit Hall C			Systems II	
1	DW		Exhibit Hall C		FS		Exhibit Hall C
1	DX	Marie Control of the	Exhibit Hall C		FT	Magnetization Dynamics and Damping III	Exhibit Hall C
			encondition at another:		FU	Dynamics in Microstructures	Exhibit Hall C
4 00pm	DZ	Plenary session: Electronic Holography Imaging	Salon 2 and 3		FV	Spin-Torque Junctions and Materials	Exhibit Hall C
	174				FV	Magnetic Sensors II (not Magnetic Recording)	Exhibit Hall C
					FX	MEMS and High frequency Devices	Exhibit Hall C
				7:00 p.m	FZ	Symposium: Magnetism on the International Technology Roadmap for Senuconductors	Salon:

Friday 9.00 a.m.	GA GB	Domain Wall Devices II Symposium: Emergent phenomena în magnetic complex oxides in reduced dimensionality	Salon 2 Salon 3
	GC	Magnetic Microscopy II	Delaware
	GD	Vortex Dynamics	Virginia
	GE	Unltra Thin Films and Surface Effects II	Washington 1
	GF	Magnetic Semiconductors: Oxides	Washington 2
	GG	Motors and Actuators	Washington 3
	GH	Channel and Signal Processing	Washington 5
8:00 a.m.	GP	Hard Magnets I: R2Fe14B	Exhibit Hall C
	GQ	Critical Phenomena, Spin glasses and Frustration	Exhibit Hall C
	GR	Nanoparticles for biomedicine	Exhibit Hall C
	GS	Biomedical Applications	Exhibit Hall C
	GT	Magnetic Fluids and Separation	Exhibit Hall C
	GU	Instrumentation and Measurement techniques	Exhibit Hall C
	GV	Machine Modelling and Analysis	Exhibit Hall C
	GW	Power and Control Magnetics	Exhibit Hall C
	GX	EMI and Computational Electromagnetics	Exhibit Hall C
4	GY	Magnetic Microscopy III	Exhibit Hall C
2:00 p.m.	НА	Symposium: Competitive Memory and Storage Technologies	Salon 2
	HB	Spin Injection in Metals: Spin-Torque	Salon 3
	HC	Magnetic multilayers and thin films	Delaware
	HD	Transformers and Inductors	Virginia
	${\rm HE}$	Crystalline Soft Magnets and Domains II	Washington 1
	HF	Hard Magnets II: R2Fe14	Washington 2
	${\rm HG}$	Magnetocaloric materials III	Washington 3
	HH	Other half metals II	Washington 4



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BW-15. An external field applied MFe₂O₄ (M=Mn, Mg) nanoparticles with Mössbauer spectroscopy. S. Hyun¹, I. Shim¹ and C. Kim¹ 1. Physics. Kookmin University. SEOUL, Korea, Republic of

TUESDAY AFTERNOON 1:00 **EXHIBIT HALL C**

Session BX CRYSTALLINE SOFT MAGNETS AND DOMAINS I (POSTER SESSION)

Hans Gatzen, Chair

- BX-01. Non-contact evaluation of surface modified materials by a model-assisted hysteresis measurement technique. C. Lo¹ J Center for NDE, lowa State University, Ames. IA
- BX-02. Multiple phase transformation and resultant magnetic properties in Fe₃Pt thin films. S. Hsiao¹, S. Chen¹ and H. Lee² J Materials Science and Engineering, Feng Chia University, Taichung, Taiwan; 2. National Synchrotron Radiation Research Center, Hsinchiu, Taiwan
- BX-03. Preparation and structural characterization of FeCo epitaxial thin films on insulating single-crystal substrates.

 T. Nishiyama¹, M. Ohtake¹, F. Kirino² and M. Futamoto¹ 1.

 Faculty of Science and Engineering, Chuo University, Tokyo, Japan; 2. Graduate School of Fine Arts, Tokyo National University of Fine Arts and Music, Tokyo, Japan
- BX-04. Change of magnetic properties of a Cold Rolled and
 Thermally Aged Fe-Cu Alloy. D.G. Park¹, C.S. Angani^{1,4},
 K.S. Ryu², S. Kobayashi³ and S. Takahashi³ I. Nuclear Materials
 Research Division, Korea Atomic Energy Research Institue
 (KAERI), Daejeon, Korea, Republic of, 2. Korea Research
 Institute of Standard Science (KRISS), Daejeon, Korea, Republic
 of; 3. NDE and Science Research Center, Iwate University,
 Morioka, Japan; 4. Department of Materials science
 Engineering, Chungnam National University(CNU), Daejeon,
 Korea, Republic of
- BX-05. Comparison of soft magnetic properties of permalloy and conetic thin films depending on Ta buffer layer. S. Lee^{1,2}, J. Choi^{1,2}, D. Hwang ^{1,2} and J. Rhee³ 1. Oriental Biomedical Engineering, Sangii University. Wonju, Gangwon-do, Korea, Republic of; 2. Eastern-western Biomedical Engineering, Sangii University, Wonju, Gangwondo, Korea, Republic of; 3. Physics, Sookmyung Women 'University, Seoul, Seoul, Korea, Republic of

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- BX-14. Structural and magnetic properties of Fe50Mn50
 nanocrystalline alloys.K. Tarigan¹, Y. Dong Scok², . KwangKwyun¹, . Suhk Kun¹ and . Seong Cho³ I. Physics, Chungbuk
 National University, Cheongju, Chungbuk, Korea, Republic of; 2.
 Physics Division, School of Science Education, Chungbuk
 National University, Cheongju, Chungbuk, Korea, Republic of
- BX-15. Improvement of high-frequency characteristics by pinning effect of thin Cr interlayers in FeCoTa films. S. Li^{1,2}, J. Duh³, S. Tsai⁴, Z. Tian⁵ and J. Lia⁶ I. Department of Physics, Fufian Normal University, Fuzhou, China; 2. National Laboratory of Solid State Microstructure, Nanjing University, Nanjing, China.
 3. Department of Materials Science and Engineering, National Tsing Hua University, Hsinchu, Taiwan; 4. EPMA Lab, Precision Instrument Center, National Tsing Hua University, Hsinchu, Taiwan; 5. College of Mechanical and Electrical Engineering, Nanjing University of Aeronautics and Astronautics, Nanjing, China; 6. Department of Physics, University of Texas at Arlington, Arlington, TX
- BX-16. Crystalline analysis of Permalloy narrow wires subject to current pulses. Y Togawa^{1,2}, T. Kimura^{2,3}, K. Harada^{2,4}, T. Akashi⁵, A. Tonomura^{2,4}, S. Mori and Y. Otani^{2,3} I. Nanoscience and Nanotechnology Research Center, Osaka Prefecture University, Sakai, Osaka, Japan; 2. Advanced Science Institute, Institute of Physical and Chemical Research (RIKEN). Wako, Saitama, Japan; 3. Institute for Solid State Physics, University of Tokyo, Kashiwa, Chiba, Japan; 4. Advanced Research Loboratory, Hitachi, Ltd., Hatoyama, Saitama, Japan, 5. Hitachi High-Technologies Co., Hitachinaka, Iharaki, Japan

TUESDAY AFTERNOON 1:00 **EXHIBIT HALL C**

Session BY NEW APPLICATIONS (POSTER SESSION)

Jin-Wei Tioh, Chair

- BY-01. Current-controlled, high-speed magneto-optic switching. S. Kemmet¹, M. Mina¹ and R.J. Weber¹ I Electrical and Computer Engineering, Iowa State University, Ames, IA
- BY-02. All-optical Integrated Switch Utilizing Faraday Rotation. J. Tioh¹, M. Mina¹ and R.J. Weber¹ I. Iowa State University, Ames. IA

BY-03. Withdrawn

BY-04. Novel solder-magnetic particle composites, their reflow using AC magnetic fields. A.H. Habib¹, M.G. Ondeck¹, K.J. Miller¹, R. Swaminathan² and M.E. McHenry¹. I Materials Sc. and Engg. Curnegie Mellon University, Pittsburgh, PA, 2. Intel Corp., Chandler, 47.

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